ON Semiconductor

Is Now

Onsemi

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NPN Silicon Power Transistors High Voltage Planar

The MJW18020 planar High Voltage Power Transistor is specifically Designed for motor control applications, high power supplies and UPS's for which the high reproducibility of DC and Switching parameters minimizes the dead time in bridge configurations.

Features

- High and Excellent Gain Linearity
- Fast and Very Tight Switching Times Parameters t_{si} and t_{fi}
- Very Stable Leakage Current due to the Planar Structure
- High Reliability
- Pb-Free Package is Available*

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Sustaining Voltage	V _{CEO}	450	Vdc
Collector-Emitter Breakdown Voltage	V _{CES}	1000	Vdc
Collector-Base Voltage	V _{CBO}	1000	Vdc
Emitter-Base Voltage	V _{EBO}	9.0	Vdc
Collector Current – Continuous – Peak (Note 1)	Ι _C	30 45	Adc
Base Current – Continuous – Peak (Note 1)	Ι _Β	6.0 10	Adc
Total Power Dissipation @ $T_C = 25^{\circ}C$ Derate Above 25°C	PD	250 2.0	W W/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-65 to +150	°C

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	0.5	°C/W
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	50	°C/W
Maximum Lead Temperature for Soldering Purposes: 1/8" from Case for 5 Seconds	ΤL	275	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

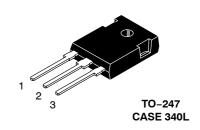
1. Pulse Test: Pulse Width = 5 μ s, Duty Cycle \leq 10%.



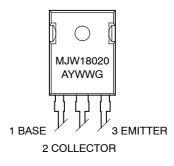
ON Semiconductor®

http://onsemi.com

30 AMPERES 1000 VOLTS BV_{CES} 450 VOLTS BV_{CEO,} 250 WATTS



MARKING DIAGRAM



A = Assembly Location Y = Year

- WW = Work Week G = Pb-Free Pack
 - = Pb-Free Package

ORDERING INFORMATION

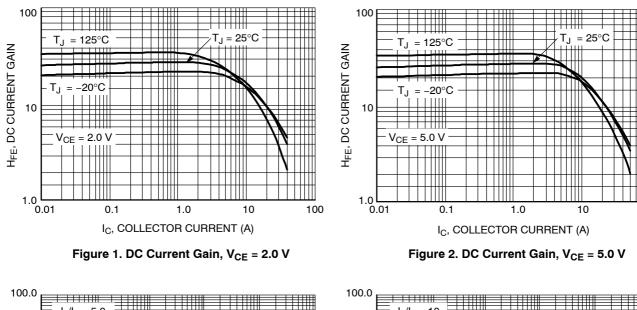
Device	Package	Shipping
MJW18020	TO-247	30 Units/Rail
MJW18020G	TO–247 (Pb–Free)	30 Units/Rail

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

Y = Year WW = Work We

ELECTRICAL CHARACTERISTICS ($T_C = 25^{\circ}C$ unless otherwise noted)

Characte	eristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS						
Collector–Emitter Sustaining Voltage $(I_{C} = 100 \text{ mAdc}, I_{B} = 0)$	V _{CEO(sus)}	450	-	-	Vdc	
Collector Cutoff Current (V_{CE} = Rated V_{CEO} , I_B = 0)	I _{CEO}	-	-	100	μAdc	
Collector Cutoff Current (V _{CE} = Rated V _C ($T_C = 125^{\circ}C$)	ICES	-	_	100 500	μAdc	
Emitter Cutoff Current ($V_{CE} = 9 \text{ Vdc}, I_C = 0$)	I _{EBO}	-	_	100	μAdc	
ON CHARACTERISTICS						
DC Current Gain $(I_C = 3 \text{ Adc}, V_{CE} = 5 (I_C = 10 \text{ Adc} V_{CE} = 3 (I_C = 10 \text{ Adc} V_{CE} = $	(T _C = 125°C) 2 Vdc)	h _{FE}	14 - 8	30 16	34 _	
$(I_{C} = 20 \text{ Adc } V_{CE} = 2)$	(T _C = 125°C)		5 5.5 4	14 9 7	- -	
$(I_{C} = 10 \text{ mAdc } V_{CE} =$ Base-Emitter Saturation Voltage $(I_{C} = 1)$	0 Adc, I _B = 2 Adc)	V _{BE(sat)}	14	25 0.97	- 1.25	Vdc
$(I_{C} = 20 \text{ Adc}, I_{B} = 4 \text{ Adc})$ Collector-Emitter Saturation Voltage		V _{CE(sat)}		1.15	1.5	Vdc
(I _C = 10 Adc, I _B = 2 Adc) (I _C = 20 Adc, I _B = 4 Adc)	(T _C = 125°C) (T _C = 125°C)		- - -	0.2 0.3 0.5 0.9	0.6 _ 1.5 2.0	
DYNAMIC CHARACTERISTICS	(10 - 123 0)		_	0.9	2.0	
Current Gain Bandwidth Product ($I_C = 1 \text{ Adc}, V_{CE} = 10 \text{ Vdc}, f_{\text{test}} = 1 \text{ MHz}$)		f _T	-	13	-	MHz
Output Capacitance (V _{CB} = 10 Vdc, I _E = 0, f _{test} = 1 MHz)		C _{ob}	-	300	500	pF
Input Capacitance (V _{EB} = 8.0)	C _{ib}	-	7000	9000	pF	
SWITCHING CHARACTERISTICS: Res	istive Load (D.C. = 10%, Pulse Width	= 70 μs)	I			
Turn-On Time			-	540	750	ns
Storage Time	-	t _s	-	4.75	6	μs
Fall Time	-	t _f	-	380	500	ns
Turn-Off Time		t _{Off}	-	5.2	6.5	μs
Turn-On Time	$(I_{C}= 20 \text{ Adc}, I_{B1} = I_{B2} = 4 \text{ Adc},$	t _{On}	-	965	1200	ns
$V_{CC} = 125 V$		t _s	-	2.9	3.5	μs
Storage Time				1	500	ns
Storage Time Fall Time	_	t _f	-	350	500	
-	-	t _f t _{Off}	-	350 3.25	4	μs
Fall Time	uctive Load (V _{clamp} = 300 V , Vcc = 15	t _{Off}				μs
Fall Time Turn-Off Time	uctive Load (V _{clamp} = 300 V , Vcc = 15 (I _C = 10 Adc, I _{B1} = I _{B2} = 2 Adc)	t _{Off}				μs ns
Fall Time Turn-Off Time SWITCHING CHARACTERISTICS: Indu Fall Time		t _{Off} 5 V, L = 200 μH)	-	3.25	4	
Fall Time Turn-Off Time SWITCHING CHARACTERISTICS: Indu		t _{Off} 5 V, L = 200 μH) t _{fi}	-	3.25 142	4 250	ns
Fall Time Turn-Off Time SWITCHING CHARACTERISTICS: Indu Fall Time Storage Time		t _{Off} 5 V, L = 200 μH) t _{fi} t _{si}	-	3.25 142 4.75	4 250 6	ns μs
Fall Time Turn-Off Time SWITCHING CHARACTERISTICS: Indu Fall Time Storage Time Crossover Time	$(I_{C} = 10 \text{ Adc}, I_{B1} = I_{B2} = 2 \text{ Adc})$	t_{Off} 5 V, L = 200 µH) t_{fi} t_{Si} t_{C}	- - -	3.25 142 4.75 320	4 250 6 500	ns μs ns



TYPICAL CHARACTERISTICS

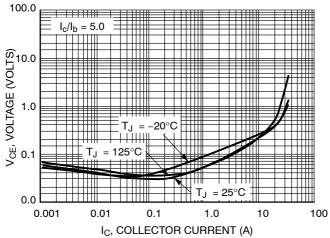
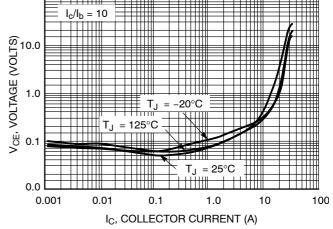


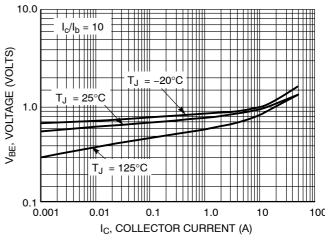
Figure 3. Typical Collector–Emitter Saturation Voltage, $I_C/I_B = 5.0$

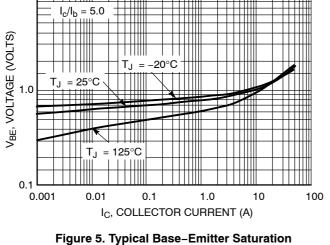
10.0



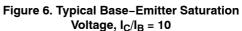
100

Figure 4. Typical Collector–Emitter Saturation Voltage, $I_C/I_B = 10$





Voltage, $I_C/I_B = 5.0$



TYPICAL CHARACTERISTICS

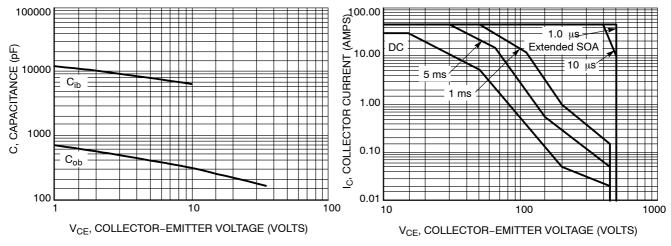


Figure 7. Typical Capacitance

Figure 8. Forward Bias Safe Operating Area

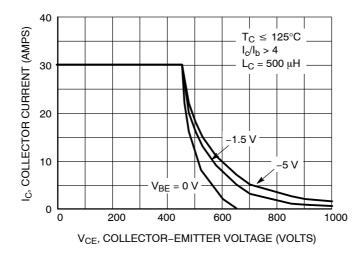
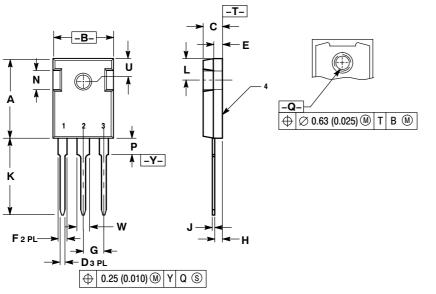


Figure 9. Reverse Bias Safe Operating Area

PACKAGE DIMENSIONS

TO-247 CASE 340L-02 ISSUE E



NOTES:

 DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

2. CONTROLLING DIMENSION: MILLIMETER.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
Α	20.32	21.08	0.800	8.30
В	15.75	16.26	0.620	0.640
C	4.70	5.30	0.185	0.209
D	1.00	1.40	0.040	0.055
Ε	1.90	2.60	0.075	0.102
F	1.65	2.13	0.065	0.084
G	5.45 BSC		0.215 BSC	
Н	1.50	2.49	0.059	0.098
J	0.40	0.80	0.016	0.031
K	19.81	20.83	0.780	0.820
L	5.40	6.20	0.212	0.244
N	4.32	5.49	0.170	0.216
Ρ		4.50		0.177
Q	3.55	3.65	0.140	0.144
U	6.15 BSC		0.242 BSC	
W	2.87	3.12	0.113	0.123

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